

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor dates sheds, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor dates sheds and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use on similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor and its officers, employees, subsidiaries, affliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out or i, directly or indirectly, any lange of the applicatio customer's to unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the

June 2012

FAIRCHILD SEMICONDUCTOR®

FSL156MRIN Green-Mode Fairchild Power Switch (FPS™)

Features

- Advanced Soft Burst Mode for Low Standby Power and Low Audible Noise
- Random Frequency Fluctuation (RFF) for Low EMI
- Pulse-by-Pulse Current Limit
- Overload Protection (OLP), Over-Voltage Protection (OVP), Abnormal Over-Current Protection (AOCP), Internal Thermal Shutdown (TSD) with Hysteresis, Output-Short Protection (OSP), and Under-Voltage Lockout (UVLO) with Hysteresis, Line Over Voltage Protection (LOVP)
- Low Operating Current (0.4mA) in Burst Mode
- Internal Startup Circuit
- Internal High-Voltage SenseFET: 650V
- Built-in Soft-Start: 15ms
- Auto-Restart Mode

Applications

 Power Supply for Home Appliances, LCD Monitors, STBs, and DVD Players

Description

The FSL156MRIN is an integrated Pulse Width Modulation (PWM) controller and SenseFET specifically designed for offline Switched Mode Power Supplies (SMPS) with minimal external components. The PWM controller includes an integrated fixed-frequency oscillator, Line-Over Voltage Protection (LOVP), Under-Voltage Lockout (UVLO), Leading-Edge Blanking (LEB), optimized gate driver, internal soft-start, temperaturecompensated precise current sources for loop compensation, and self-protection circuitry. Compared with a discrete MOSFET and PWM controller solution, the FSL156MRIN reduces total cost, component count, size, and weight; while simultaneously increasing efficiency, productivity, and system reliability. This device provides a basic platform suited for cost-effective design of a flyback converter.

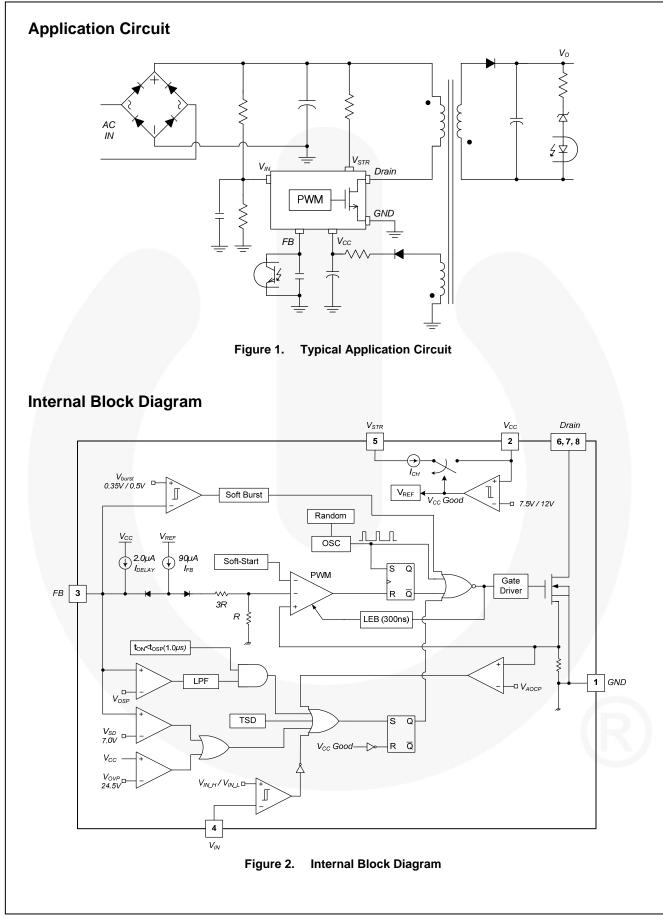
Ordering Information

		Operating Junction	LIIIII		Output Power Table ⁽²⁾			
Part Number	Package ⁽¹⁾			(Max.)	230V _{AC} ±15%		85-265V _{AC}	
	J	Temperature			Adapter ⁽³⁾	Open Frame ⁽⁴⁾	Adapter ⁽³⁾	Open Frame ⁽⁴⁾
FSL156MRIN	8-DIP	−40°C ~ +125°C	1.6A	2.2Ω	26W	40W	20W	30W

Notes:

1. Lead-free package per JEDEC J-STD-020B.

- 2. The junction temperature can limit the maximum output power.
- 3. Typical continuous power in a non-ventilated enclosed adapter measured at 50°C ambient temperature.
- 4. Maximum practical continuous power in an open-frame design at 50°C ambient temperature.





Pin Configuration

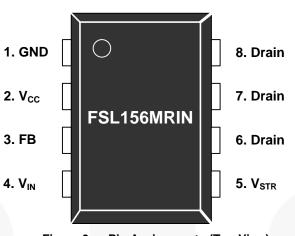


Figure 3. Pin Assignments (Top View)

Pin Definitions

Pin #	Name	Description		
1	GND	Ground. This pin is the control ground and the SenseFET source.		
2	Vcc	Power Supply . This pin is the positive supply input, which provides the internal operating current for both startup and steady-state operation.		
3	FB	Feedback . This pin is internally connected to the inverting input of the PWM comparator. The collector of an opto-coupler is typically tied to this pin. For stable operation, a capacitor should be placed between this pin and GND. If the voltage of this pin reaches 7V, the overload protection triggers, which shuts down the FPS.		
4	V _{IN}	ine Over-Voltage Input . This pin is the input pin of line voltage. The voltage, which is livided by resistors, is the input of this pin. If this pin voltage is higher than V _{INH} voltage, the .OVP triggers, which shuts down the FPS. Do not leave this pin floating. If LOVP is not used, his pin should be directly connected to the GND.		
5	V _{STR}	Startup . This pin is connected directly, or through a resistor, to the high-voltage DC link. At startup, the internal high-voltage current source supplies internal bias and charges the external capacitor connected to the V_{CC} pin. Once V_{CC} reaches 12V, the internal current source (I_{CH}) is disabled.		
6				
7	Drain	SenseFET Drain. High-voltage power SenseFET drain connection.		
8				

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol		Min.	Max.	Unit		
V _{STR}	V _{STR} Pin Voltage				650	V
V _{DS}	Drain Pin Voltage				650	V
V _{CC}	V _{CC} Pin Voltage				26	V
V_{FB}	Feedback Pin Voltage			-0.3	10.0	V
V _{IN}	V _{IN} Pin Voltage			-0.3	10.0	V
I _{DM}	Drain Current Pulsed				4	А
	Osetisus Ositatian D		T _C =25°C		1.90	
I _{DS}	Continuous Switching D		1.27	A		
E _{AS}	Single-Pulsed Avalanche Energy ⁽⁶⁾				190	mJ
PD	Total Power Dissipation (T _C =25°C) ⁽⁷⁾				1.5	W
-	Maximum Junction Temperature				150	°C
TJ	Operating Junction Temperature ⁽⁸⁾				+125	°C
T _{STG}	Storage Temperature			-55	+150	°C
505	Electrostatic Discharge	Human Body Model, JESD22-A114			4.5	1.) (
ESD	Capability Charged Device Model, JESD22-C101				2.0	kV

Notes:

5. Repetitive peak switching current when the inductive load is assumed: limited by maximum duty (D_{MAX}=0.73) and junction temperature (see Figure 4).

6. L=45mH, starting T_J =25°C.

- 7. Infinite cooling condition (refer to the SEMI G30-88).
- 8. Although this parameter guarantees IC operation, it does not guarantee all electrical characteristics.

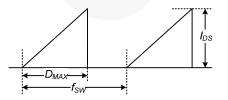


Figure 4. Repetitive Peak Switching Current

Thermal Impedance

T_A=25°C unless otherwise specified.

Symbol	Parameter		Unit
θ _{JA}	Junction-to-Ambient Thermal Impedance ⁽⁹⁾		°C/W
Ψ_{JL}	Junction-to-Lead Thermal Impedance ⁽¹⁰⁾		°C/W

Notes:

9. JEDEC recommended environment, JESD51-2, and test board, JESD51-10, with minimum land pattern.

10. Measured on drain pin #7, close to the plastic interface.

Electrical Characteristics

 T_J = 25°C unless otherwise specified.

Symbol	Parameter		Conditions	Min.	Тур.	Max.	Unit
SenseFET	Section				1		
BV _{DSS}	Drain-Source Breakdown Voltage		V _{CC} =0V, I _D =250μA	650			V
I _{DSS}	Zero-Gate-Voltage Drain Current		V _{DS} =520V, T _A =125°C			250	μA
R _{DS(ON)}	Drain-Source On-	State Resistance	V _{GS} =10V, I _D =1A		1.8	2.2	Ω
CISS	Input Capacitance	e ⁽¹¹⁾	V _{DS} =25V, V _{GS} =0V, f=1MHz		515		pF
C _{OSS}	Output Capacitan		V _{DS} =25V, V _{GS} =0V, f=1MHz		75		pF
tr	Rise Time		V _{DS} =325V, I _D =4A, R _G =25Ω		26		ns
t _f	Fall Time		V _{DS} =325V, I _D =4A, R _G =25Ω		25		ns
t _{d(on)}	Turn-On Delay		V _{DS} =325V, I _D =4A, R _G =25Ω		14		ns
t _{d(off)}	Turn-Off Delay		V_{DS} =325V, I_{D} =4A, R_{G} =25 Ω		32	s	ns
Control Se	ction						
f _S	Switching Freque	ncy ⁽¹¹⁾	V _{CC} =14V, V _{FB} =4V	61	67	73	kHz
∆fs	Switching Freque	ncy Variation ⁽¹¹⁾	−25°C < T _J < 125°C		±5	±10	%
D _{MAX}	Maximum Duty R		V _{CC} =14V, V _{FB} =4V	61	67	73	%
D _{MIN}	Minimum Duty Ra	atio	V _{CC} =14V, V _{FB} =0V			0	%
I _{FB}	Feedback Source Current		V _{FB} =0	65	90	115	μA
V _{START}	UVLO Threshold Voltage		V _{FB} =0V, V _{CC} Sweep	11	12	13	V
VSTOP			After Turn-on, V _{FB} =0V	7.0	7.5	8.0	V
t _{ss}	Internal Soft-Start Time		V _{STR} =40V, V _{CC} Sweep		15		ms
VRECOMM	Recommended V _{CC} Range			13		23	V
Burst Mode	e Section						
V _{BURH}				0.45	0.50	0.55	V
VBURL	Burst-Mode Volta	ge	V_{CC} =14V, V_{FB} Sweep	0.30	0.35	0.40	V
Hys		-			150		mV
Protection	Section						7
ILIM	Peak Drain Curre	nt Limit	di/dt=300mA/µs	1.45	1.60	1.75	Α
V _{SD}	Shutdown Feedba	ack Voltage	V _{CC} =14V, V _{FB} Sweep	6.45	7.00	7.55	V
IDELAY	Shutdown Delay (V _{CC} =14V, V _{FB} =4V	1.2	2.0	2.8	μA
t _{LEB}	Leading-Edge Bla	anking Time ^(11,12)			300		ns
VOVP	Over-Voltage Pro		V _{CC} Sweep	23.0	24.5	26.0	V
V _{INH}	Line Over-Voltage		V _{CC} =14V, V _{IN} Sweep	1.87	1.95	2.03	V
VINHYS	Line Over-Voltage Hysteresis	e Protection	V _{CC} =14V, V _{IN} Sweep		0.06		V
t _{OSP}		hreshold Time	OSP Triggered when	0.7	1.0	1.3	μs
V _{OSP}	Output-Short Protection ⁽¹¹⁾	hreshold V _{FB}	ton <tosp &="" vfb="">VOSP</tosp>	1.8	2.0	2.2	V
t _{OSP_FB}		VFB Blanking Time	(Lasts Longer than t _{OSP_FB})	2.0	2.5	3.0	μs
TSD	-	– (11)	Shutdown Temperature	125	135	145	°C
T _{HYS}	I hermal Shutdow	n Temperature ⁽¹¹⁾	Hysteresis	1	60		°C

Continued on the following page...

Electrical Characteristics (Continued)

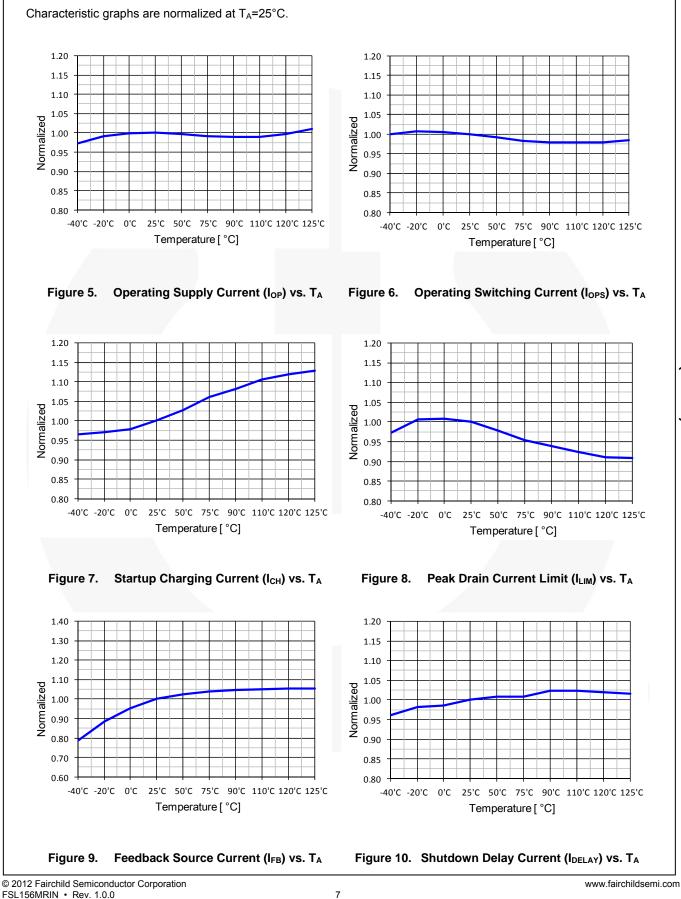
 $T_{\rm J}$ = 25°C unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit	
Total Devic	otal Device Section						
I _{OP}	Operating Supply Current, (Control Part in Burst Mode)	V _{CC} =14V, V _{FB} =0V	0.3	0.4	0.5	mA	
I _{OPS}	Operating Switching Current, (Control Part and SenseFET Part)	V _{CC} =14V, V _{FB} =2V	1.1	1.5	1.9	mA	
I _{START}	Start Current	V _{CC} =11V (Before V _{CC} Reaches V _{START})	85	120	155	μA	
I _{CH}	Startup Charging Current	V _{CC} =V _{FB} =0V, V _{STR} =40V	0.7	1.0	1.3	mA	
V _{STR}	Minimum V _{STR} Supply Voltage	V _{CC} =V _{FB} =0V, V _{STR} Sweep		26		V	

Notes:

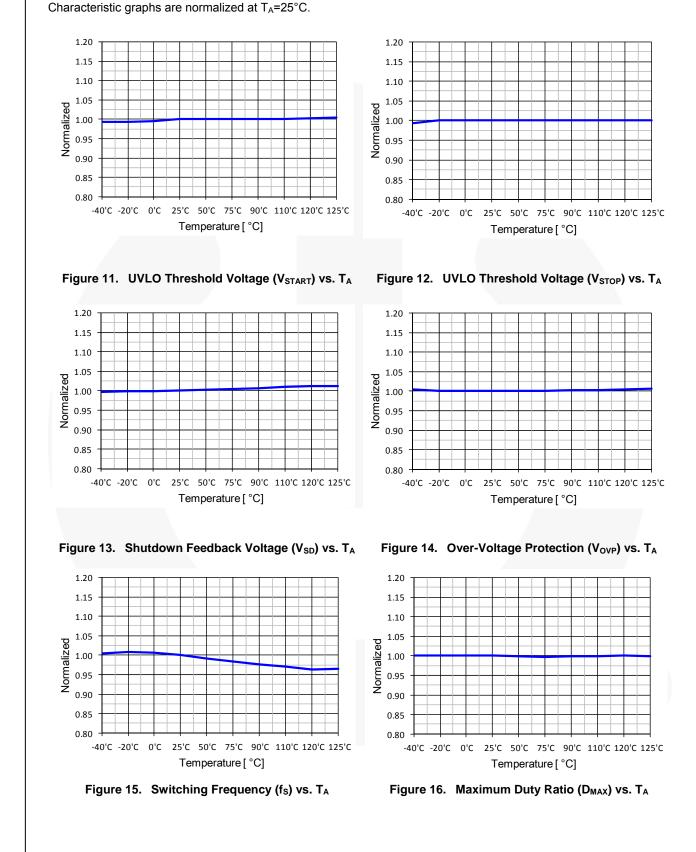
11. These parameters are guaranteed; not 100% tested in production.

12. t_{LEB} includes gate turn-on time.

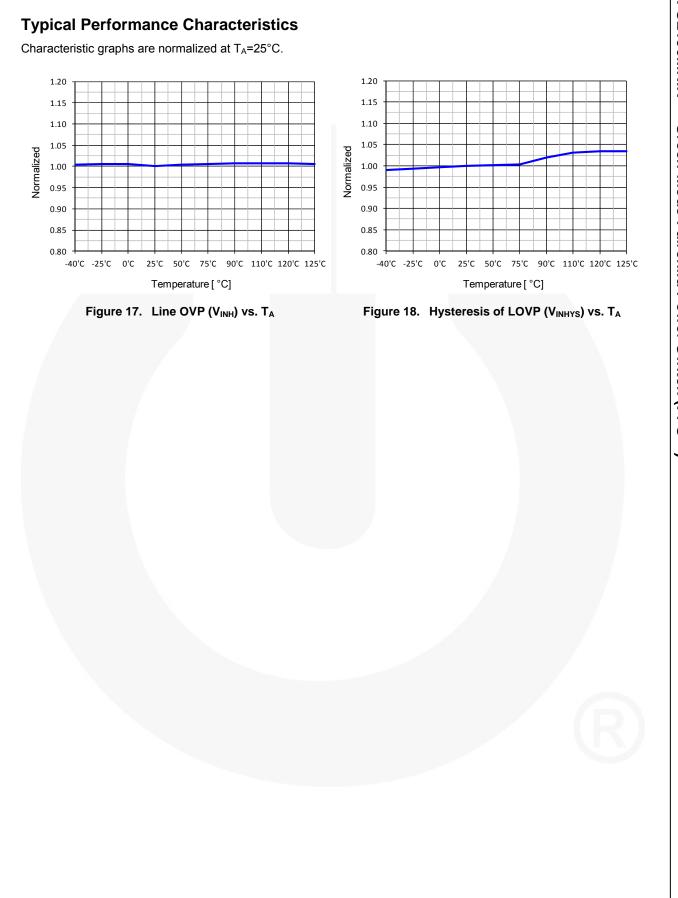


Typical Performance Characteristics

7



Typical Performance Characteristics



Functional Description

1. Startup: At startup, an internal high-voltage current source supplies the internal bias and charges the external capacitor (C_{VCC}) connected to the V_{CC} pin, as illustrated in Figure 19. When V_{CC} reaches 12V, the FSL156MRIN begins switching and the internal high-voltage current source is disabled. Normal switching operation continues and the power is supplied from the auxiliary transformer winding unless V_{CC} goes below the stop voltage of 7.5V.

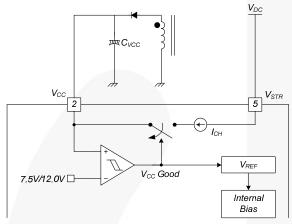


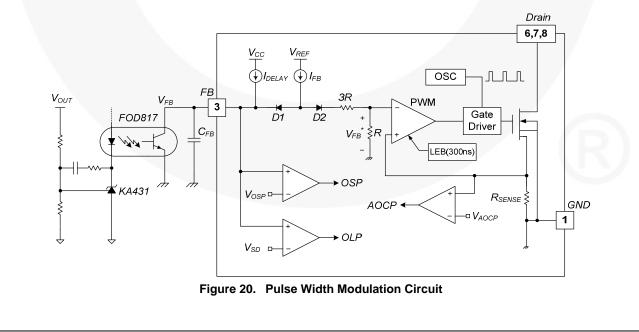
Figure 19. Startup Block

2. Soft-Start: The internal soft-start circuit increases PWM comparator inverting input voltage, together with the SenseFET current, slowly after startup. The typical soft-start time is 15ms. The pulse width to the power switching device is progressively increased to establish the correct working conditions for the transformers, inductors, and capacitors. The voltage on the output capacitors is progressively increased to smoothly establish the required output voltage. This helps prevent transformer saturation and reduces stress on the secondary diode during startup.

3. Feedback Control: This device employs Current-Mode control, as shown in Figure 20. An opto-coupler (such as the FOD817) and shunt regulator (such as the KA431) are typically used to implement the feedback network. Comparing the feedback voltage with the voltage across the R_{SENSE} resistor makes it possible to control the switching duty cycle. When the reference pin voltage of the shunt regulator exceeds the internal reference voltage of 2.5V, the opto-coupler LED current increases, pulling down the feedback voltage and reducing drain current. This typically occurs when the input voltage is increased or the output load is decreased.

3.1 Pulse-by-Pulse Current Limit: Because Current-Mode control is employed, the peak current through the SenseFET is limited by the inverting input of PWM comparator (V_{FB}*), as shown in Figure 20. Assuming that the 90µA current source flows only through the internal resistor (3R + R =25kΩ), the cathode voltage of diode D2 is about 2.8V. Since D1 is blocked when the feedback voltage (V_{FB}) exceeds 2.8V, the maximum voltage of the cathode of D2 is clamped at this voltage. Therefore, the peak value of the current through the SenseFET is limited.

3.2 Leading-Edge Blanking (LEB): At the instant the internal SenseFET is turned on, a high-current spike usually occurs through the SenseFET, caused by primary-side capacitance and secondary-side rectifier reverse recovery. Excessive voltage across the R_{SENSE} resistor leads to incorrect feedback operation in Current-Mode PWM control. To counter this effect, the LEB circuit inhibits the PWM comparator for t_{LEB} (300ns) after the SenseFET is turned on.



FSL156MRIN — Green-Mode Fairchild Power Switch (FPS™)

4. Protection Circuits: The FSL156MRIN has several self-protective functions, such as Overload Protection (OLP), Abnormal Over-Current Protection (AOCP), Output-Short Protection (OSP), Over-Voltage Protection (OVP), and Thermal Shutdown (TSD). All the protections are implemented as auto-restart. Once the fault condition is detected, switching is terminated and the SenseFET remains off. This causes V_{CC} to fall. When V_{CC} falls to the Under-Voltage Lockout (UVLO) stop voltage of 7.5V, the protection is reset and the startup circuit charges the V_{CC} capacitor. When V_{CC} reaches the start voltage of 12.0V, normal operation resumes. If the fault condition is not removed, the SenseFET remains off and V_{CC} drops to stop voltage again. In this manner, the auto-restart can alternately enable and disable the switching of the power SenseFET until the fault condition is eliminated. Because these protection circuits are fully integrated into the IC without external components, reliability is improved without increasing cost.

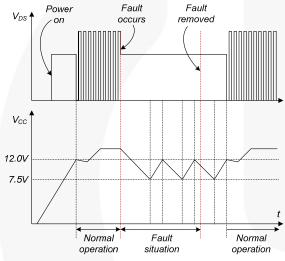
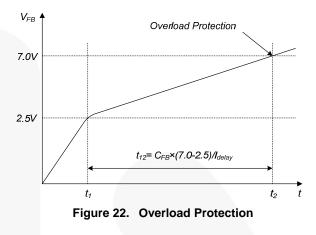


Figure 21. Auto-Restart Protection Waveforms

4.1 Overload Protection (OLP): Overload is defined as the load current exceeding its normal level due to an unexpected abnormal event. In this situation, the protection circuit should trigger to protect the SMPS. However, even when the SMPS is in normal operation, the overload protection circuit can be triggered during the load transition. To avoid this undesired operation, the overload protection circuit is designed to trigger only after a specified time to determine whether it is a transient situation or a true overload situation. Because of the pulse-by-pulse current-limit capability, the maximum peak current through the SenseFET is limited and, therefore, the maximum input power is restricted with a given input voltage. If the output consumes more than this maximum power, the output voltage (VOUT) decreases below the set voltage. This reduces the current through the opto-coupler LED, which also reduces the opto-coupler transistor current, increasing the feedback voltage (VFB). If VFB exceeds 2.5V, D1 is blocked and the 2.0µA current source starts to charge CFB slowly up. In this condition, VFB continues

increasing until it reaches 7.0V, when the switching operation is terminated, as shown in Figure 22. The delay for shutdown is the time required to charge C_{FB} from 2.5V to 7.0V with 2.0 μ A. A 25 ~ 50ms delay is typical for most applications. This protection is implemented as auto-restart.



4.2 Abnormal Over-Current Protection (AOCP): When the secondary rectifier diodes or the transformer pins are shorted, a steep current with extremely high di/dt can flow through the SenseFET during the minimum turn-on time. Even though the FSL156MRIN has overload protection, it is not enough to protect the FSL156MRIN in that abnormal case; due to the severe current stress imposed on the SenseFET until OLP is triggered. The internal AOCP circuit is shown in Figure 23. When the gate turn-on signal is applied to the power SenseFET, the AOCP block is enabled and monitors the current through the sensing resistor. The voltage across the resistor is compared with a preset AOCP level. If the sensingresistor voltage is greater than the AOCP level, the set signal is applied to the S-R latch, resulting in the shutdown of the SMPS.

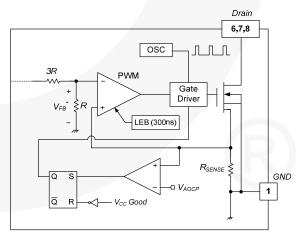


Figure 23. Abnormal Over-Current Protection

4.3. Output-Short Protection (OSP): If the output is shorted, steep current with extremely high di/dt can flow through the SenseFET during the minimum turnon time. Such a steep current creates high-voltage stress on the drain of the SenseFET when turned off. To protect the device from this abnormal condition, OSP is included. It is comprised of detecting V_{FB} and SenseFET turn-on time. When the V_{FB} is higher than 2.0V and the SenseFET turn-on time is lower than 1.0µs, this condition is recognized as an abnormal error and PWM switching shuts down until V_{CC} reaches V_{START} again. An abnormal condition output short is shown in Figure 24.

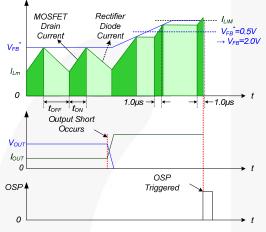


Figure 24. Output-Short Protection

4.4 Over-Voltage Protection (OVP): If the secondary-side feedback circuit malfunctions or a solder defect causes an opening in the feedback path, the current through the opto-coupler transistor becomes almost zero. Then VFB climbs up in a similar manner to the overload situation, forcing the preset maximum current to be supplied to the SMPS until the overload protection is triggered. Because more energy than required is provided to the output, the output voltage may exceed the rated voltage before the overload protection is triggered, resulting in the breakdown of the devices in the secondary side. To prevent this situation, an OVP circuit is employed. In general, the V_{CC} is proportional to the output voltage and the FSL156MRIN uses V_{CC} instead of directly monitoring the output voltage. If V_{CC} exceeds 24.5V, an OVP circuit is triggered, resulting in the termination of the switching operation. To avoid undesired activation of OVP during normal operation, V_{CC} should be designed to be below 24.5V.

4.5 Thermal Shutdown (TSD): The SenseFET and the control IC on a die in one package makes it easier for the control IC to detect the temperature of the SenseFET. If the temperature exceeds ~135°C, the thermal shutdown is triggered and stops operation. The FSL156MRIN operates in Auto-Restart Mode until the temperature decreases to around 75°C, when normal operation resumes.

4.6 Line Over-Voltage Protection (LOVP): If the line input voltage is increased to an unwanted level, high line input voltage creates high-voltage stress on the entire system. To protect from this abnormal condition, LOVP is included. It is comprised of detecting V_{IN} using divided resistors. When V_{IN} is higher than 1.95V, this condition is recognized as an abnormal error and PWM switching shuts down until V_{IN} decreases to around 1.89V (60mV hysteresis).

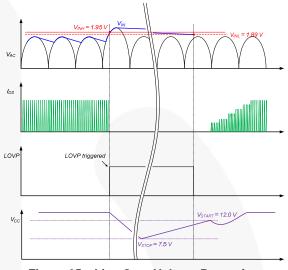
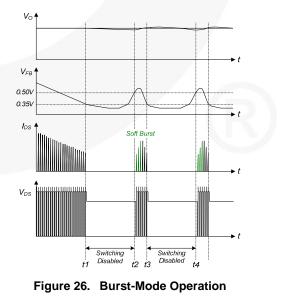


Figure 25. Line Over-Voltage Protection

5. Soft Burst Mode: To minimize power dissipation in Standby Mode, the FSL156MRIN enters Burst-Mode operation. As the load decreases, the feedback voltage decreases. As shown in Figure 22, the device automatically enters Burst Mode when the feedback voltage drops below V_{BURL} (350mV). At this point, switching stops and the output voltages start to drop at a rate dependent on standby current load. This causes the feedback voltage to rise. Once it passes V_{BURH} (500mV), switching resumes. The feedback voltage then falls and the process repeats. Burst Mode alternately enables and disables SenseFET switching, reducing switching loss in Standby Mode.



FSL156MRIN — Green-Mode Fairchild Power Switch (FPS[™])

6. Random Frequency Fluctuation (RFF): Fluctuating switching frequency of an SMPS can reduce EMI by spreading the energy over a wide frequency range. The amount of EMI reduction is directly related to the switching frequency variation, which is limited internally. The switching frequency is determined randomly by external feedback voltage and an internal free-running oscillator at every switching instant. RFF effectively scatters EMI noise around typical switching frequency (67kHz) and can reduce the cost of the input filter included to meet the EMI requirements (e.g. EN55022).

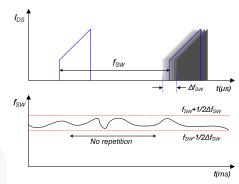
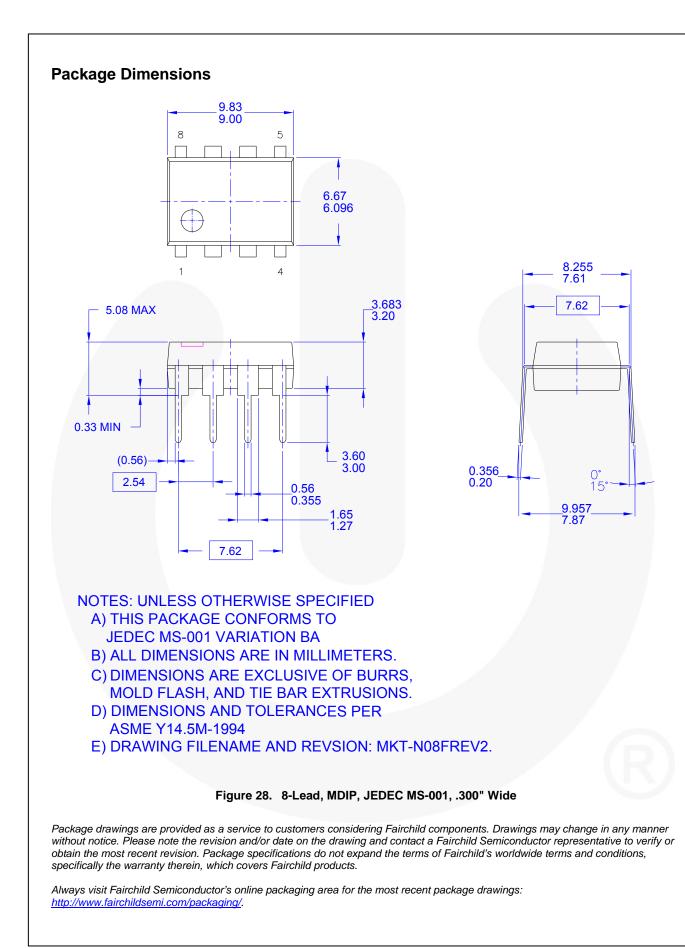


Figure 27. Random Frequency Fluctuation



FAIRCHILD SEMICONDUCTOR TRADEMARKS The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks. PowerTrench® The Power Franchise® 2Cool™ F-PFS™ PowerXS™ AccuPower™ FRFET® wer p, Global Power ResourceSM AX-CAP™* Programmable Active Droop™ franch GreenBridge™ **OFFT**[®] BitSiC™ TinyBoost™ Green FPS™ QSTM Build it Now™ TinyBuck™ Green FPS™ e-Series™ Ouiet Series™ CorePLUS™ TinyCalc™ Gmax™ RapidConfigure™ CorePOWER™ TinyLogic® GTO™ CROSSVOLT TINYOPTOM CTL™ IntelliMAX[™] TinyPower™ Saving our world, 1mW/W/kW at a time™ **ISOPLANAR**TM Current Transfer Logic™ TinyPWM™ SignalWise™ Making Small Speakers Sound Louder DEUXPEED SmartMax™ TinyWire™ and Better Dual Cool™ SMART START™ Tran SiC™ EcoSPARK[®] MegaBuck™ Solutions for Your Success™ TriFault Detect™ MICROCOUPLER™ EfficientMax™ SPM® TRUECURRENT®* **ESBC™** MicroFET™ STEALTH" uSerDes™ MicroPak™ SuperFET[®] MicroPak2™ SuperSOT™-3 Fairchild® Miller Drive™ SuperSOT™-6 UHC Fairchild Semiconductor® Motion Max™ SuperSOT™-8 Ultra FRFET™ FACT Quiet Series™ mWSaver™ SupreMOS® UniFET FACT OptoHiT™ FAST® SyncFET™ VCXTM **OPTOLOGIC®** Sync-Lock™ FastvCore™ VisualMax™ **OPTOPLANAR®** FETBench™ VoltagePlus™ FlashWriter®* XS™ R **FPS**Th * Trademarks of System General Corporation, used under license by Fairchild Semiconductor. DISCLAIMER FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS LIFE SUPPORT POLICY FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein: 1. Life support devices or systems are devices or systems which, (a) are 2. A critical component in any component of a life support, device, or intended for surgical implant into the body or (b) support or sustain system whose failure to perform can be reasonably expected to life, and (c) whose failure to perform when properly used in cause the failure of the life support device or system, or to affect its accordance with instructions for use provided in the labeling, can be safety or effectiveness. reasonably expected to result in a significant injury of the user. ANTI-COUNTERFEITING POLICY Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support. Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors. PRODUCT STATUS DEFINITIONS

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. 162

SL156MRIN

I

Green-Mode Fairchild Power Switch (FPS[™])

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Fairchild Semiconductor: